

Linear Systems replaces discontinued Siliconix SST4393

The SST4393 features many of the superior characteristics of JFETs which make it a good choice for demanding analog switching applications and for specialized amplifier circuits.

SST4393 Benefits:

- Low Error Voltage
- High-Speed Analog Circuit Performance
- Negligible "Off-Error," Excellent Accuracy
- Good Frequency Response, Low Glitches
- Eliminates Additional Buffering

SST4393 Applications:

- Analog Switches
- Choppers, Sample-and-Hold
- Normally "On" Switches, Current Limiters

FEATURES

DIRECT REPLACEMENT FOR SILICONIX SST4393

LOW ON RESISTANCE $r_{DS(on)} \leq 100\Omega$

LOW GATE OPERATING CURRENT $I_{D(off)} = 5\mu A$

FAST SWITCHING $t_{(ON)} \leq 15ns$

ABSOLUTE MAXIMUM RATINGS¹ @ 25°C (unless otherwise noted)

Maximum Temperatures

Storage Temperature -65°C to +200°C

Operating Junction Temperature -55°C to +200°C

Maximum Power Dissipation

Continuous Power Dissipation 350mW

MAXIMUM CURRENT

Gate Current (Note 1) $I_G = 50mA$

MAXIMUM VOLTAGES

Gate to Drain Voltage / Gate to Source Voltage -35V

SST4393 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
BV_{GSS}	Gate to Source Breakdown Voltage	-35	--	--	V	$I_G = -1\mu A, V_{DS} = 0V$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	-0.5	--	-3		$V_{DS} = 15V, I_D = 10nA$
$V_{GS(F)}$	Gate to Source Forward Voltage	--	0.7	1		$I_G = 1mA, V_{DS} = 0V$
$V_{DS(on)}$	Drain to Source On Voltage	--	0.25	--		$V_{GS} = 0V, I_D = 3mA$
$V_{DS(on)}$	Drain to Source On Voltage	--	0.3	0.4		$V_{GS} = 0V, I_D = 6mA$
$V_{DS(on)}$	Drain to Source On Voltage	--	0.35	--	mA	$V_{GS} = 0V, I_D = 12mA$
I_{DSS}	Drain to Source Saturation Current ²	5	--	--		$V_{DS} = 20V, V_{GS} = 0V$
I_{GSS}	Gate Reverse Current	--	-5	-100	pA	$V_{GS} = -20V, V_{DS} = 0V$
I_G	Gate Operating Current	--	-5	--		$V_{DS} = 15V, I_D = 10mA$
$I_{D(off)}$	Drain Cutoff Current	--	5	100		$V_{DS} = 10V, V_{GS} = -10V$
$r_{DS(on)}$	Drain to Source On Resistance	--	--	100	Ω	$V_{GS} = 0V, I_D = 1mA$

SST4393 DYNAMIC ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	TYP	MIN	MAX	UNITS	CONDITIONS
g_{fs}	Forward Transconductance	6	--	--	mS	$V_{DS} = 20V, I_D = 1mA, f = 1kHz$
g_{os}	Output Conductance	25	--	--	μS	$V_{DS} = 20V, I_D = 1mA, f = 1kHz$
$r_{ds(on)}$	Drain to Source On Resistance	--	--	100	Ω	$V_{GS} = 0V, I_D = 0A, f = 1kHz$
C_{iss}	Input Capacitance	13	--	--	pF	$V_{DS} = 20V, V_{GS} = 0V, f = 1MHz$
C_{rss}	Reverse Transfer Capacitance	3.6	--	--		$V_{DS} = 0V, V_{GS} = -5V, f = 1MHz$
C_{rss}		3.5	--	--		$V_{DS} = 0V, V_{GS} = -7V, f = 1MHz$
C_{rss}		3.1	--	--		$V_{DS} = 0V, V_{GS} = -12V, f = 1MHz$
e_n	Equivalent Input Noise Voltage	3	--	--	nV/VHz	$V_{DS} = 10V, I_D = 10mA, f = 1kHz$

SST4393 SWITCHING ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	TYP	MIN	MAX	UNITS	CONDITIONS
$t_{d(on)}$	Turn On Time	2	--	--	ns	$V_{DD} = 10V, V_{GS(H)} = 0V$
t_r		2	--	--		
$t_{d(off)}$	Turn Off Time	6	--	--		
t_f		13	--	--		

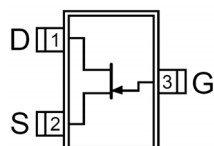
Notes: 1. Absolute ratings are limiting values above which serviceability may be impaired

2. Pulse test: PW $\leq 300\mu s$, Duty Cycle $\leq 3\%$

SST4393 SWITCHING CIRCUIT PARAMETERS

$V_{GS(L)}$	-5V
R_L	3200 Ω
$I_{D(on)}$	3mA

SOT-23 (Top View)



Available Packages:

SST4393 in SOT-23

SST4393 in bare die

Micross Components Europe

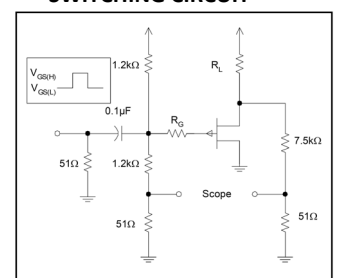


Tel: +44 1603 788967

Email: chipcomponents@micross.com

Web: <http://www.micross.com/distribution>

SWITCHING CIRCUIT



Contact Micross for full package and die dimensions